



FINAL
Examination Paper

(COVER PAGE)

Session : January 2016

Programme : Diploma in Electrical and Electronic Engineering (DEEI)

Course : EGM 1182: Structures and Properties of Material

Date of Examination : 8 March 2016 (Tuesday)

Time : 11:00am – 1:00pm

Duration : 2 Hours Reading Time : Nil

Special Instructions :

This paper consists of SIX (6) questions. Attempt any FOUR (4) questions in the answer booklet provided. All questions carry equal marks.

IMPORTANT NOTE : THIS PAPER SHOULD NOT BE TAKEN OUT OF THE EXAMINATION HALL

Materials Permitted : Nil

Materials Provided : Answer Booklet

Examiner(s) : Mr. Phua Chin Lai

Moderator : Prof. Ir. Dr. Cheong Kuan Yew

This paper consists of 5 printed pages, including the cover page.

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DIPLOMA IN ELECTRICAL AND ELECTRONIC ENGINEERING PROGRAMME (DEEI)
 EGM 1182: STRUCTURES AND PROPERTIES OF MATERIAL
 FINAL EXAMINATION: JAN 2016 SESSION

Instructions: This paper consists of **SIX (6)** questions. Attempt any **FOUR (4)** questions in the answer booklet provided. All questions carry equal marks.

Question 1

(a) All of the noble gases except helium have similar outer electron configuration. List down this similarity of outer electron configuration. (2 marks)

(b) Briefly describe the following types of secondary bonding:

- (i) fluctuating dipole,
- (ii) permanent dipole and
- (iii) between of the choice of noble gases krypton and xenon, which noble gas would be expected to have the strongest dipole bonding and why? (9 marks)

(c) A monel alloy consists of 70 wt % Ni and 30 wt % Cu. What are the atom percentages of Ni and Cu in this alloy? (9 marks)

(d) Zinc at 20°C has a hexagonal close packed (HCP) structure with atoms of diameter of 0.238 nm. Calculate the volume of unit cell of zinc. Assume that the atomic packing factor for HCP crystal structure is 0.74 (5 marks)

Question 2

(a) What are the two (2) main items of information that could be obtained from the Periodic Table of Elements? (2 marks)

(b) Determine indices for the planes in the cubic unit cell shown in Figure 2.

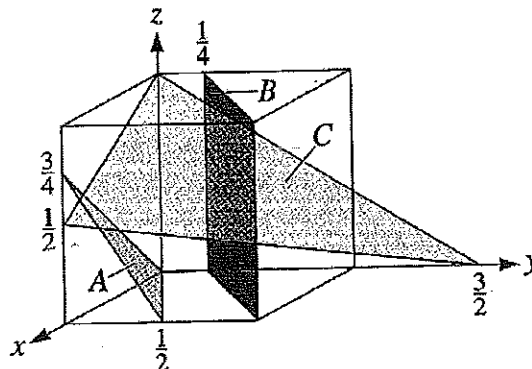


Figure 2.

(8 marks)

- (c) Calculate the planar atomic density in atoms per square millimeter for the following crystal planes in a chromium BCC structure, which has a lattice constant of 0.28846 nm:
 (i) (100), (ii) (110) (9 marks)
- (d) Describe and illustrate the solidification process of a pure metal crystal. (6 marks)

Question 3

- (a) In the solidification of a metal, what is the difference between an embryo and a nucleus? What is the critical radius of a solidifying particle? (6 marks)
- (b) Calculate the radius of the largest interstitial void in the BCC α iron lattice. The atomic radius of the iron atom in this lattice is 0.124 nm, and the largest interstitial voids occur at the position of $(\frac{1}{4}, \frac{1}{2}, 0)$; $(\frac{1}{2}, \frac{3}{4}, 0)$; $(\frac{3}{4}, \frac{1}{2}, 0)$; $(\frac{1}{2}, \frac{1}{4}, 0)$, etc. (7 marks)
- (c) Define the following terms related to the mechanical behavior of materials
 (i) Endurance limits,
 (ii) Fatigue strength,
 (iii) Engineering stress and its SI unit,
 (iv) Engineering strain and its SI unit. (8 marks)
- (d) Calculate the engineering stress in SI units on a 15-cm long bar with a cross section of 4.25 mm \times 12.0 mm and subjected to a load of 5000 kg. (4 marks)

Question 4

- (a) What are the characteristics of a fracture surface in a ductile metal? (3 marks)
- (b) What are the characteristics of a fracture surface in a brittle metal? (3 marks)
- (c) What is metal creep? (3 marks)
- (d) Phase diagram of an 88 wt% Al-12 wt% Mg alloy is shown in Figure 4. During solidification, determine
 (i) the composition of first solid to be formed,
 (ii) the amounts and compositions of each phase at 525 °C,
 (iii) the amounts and compositions of each phase at 450 °C,
 (iv) the amounts and compositions of each phase at 25 °C.

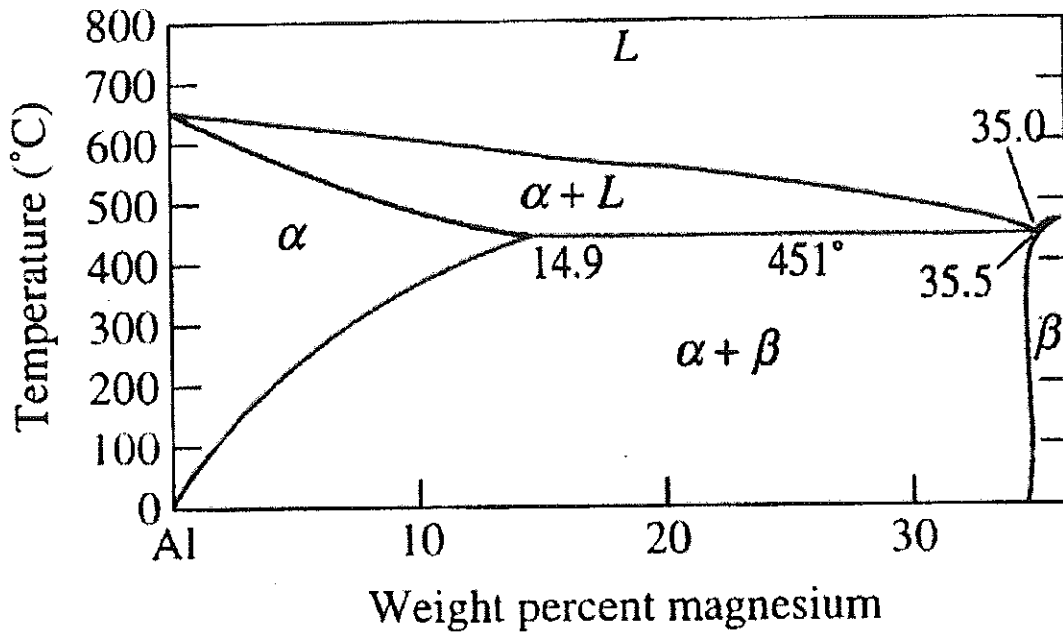


Figure 4

(16 marks)

Question 5

- (a) Distinguish between natural aging and artificial aging for a precipitation metal hardening (4 marks)
- (b) A high molecular weight polyethylene $-(C_2H_4)_n-$ has an average molecular weight of 410,000 g/mol. What is its average degree of polymerization? (5 marks)
- (c) Distinguish between a homopolymer and a copolymer. (2 marks)
- (d) Illustrate the following types of copolymers by using filled and open circles for their mers:
 (i) random,
 (ii) alternating,
 (iii) block, and
 (iv) graft. (8 marks)
- (e) List 6 mechanical properties of ceramic materials? (6 marks)

Question 6

(a) Calculate the density in grams per cubic centimeter of CsBr, which complies to the lattice constant relationship equation $a\sqrt{3} = 2(r + R)$, where a is the lattice constant and ionic radii are represented by r and R . Given the unit cell of CsBr contains one Cs^+ and one Br^- ion. Ionic radii are $\text{Cs}^+ = 0.165 \text{ nm}$ and $\text{Br}^- = 0.196 \text{ nm}$.

(5 marks)

(b) Write equations for the
 (i) macroscopic and
 (ii) microscopic forms of Ohm's law.

Define the symbols in each of the equations and indicate their SI units.

(6 marks)

(c) Phosphorus is added to make an n-type silicon semiconductor with an electrical conductivity of $250 \Omega \cdot \text{m}^{-1}$. Calculate the necessary number of charge carriers required.

(Assuming an electron mobility of $\mu_n = 0.1350 \text{ m}^2 / (\text{V}\cdot\text{s})$, and absolute value of electron or hole charge is $1.6 \times 10^{-19} \text{ C}$)

(5 marks)

(d) Twenty-cm-long rod with a diameter of 0.250 cm is loaded with a 5000 N weight. If the diameter decreases to 0.210cm, determine

- (i) the engineering strain at this load and
- (ii) the true stress and strain at this load.

(9 marks)

--THE END--

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